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Sheet 1 of 1

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First Named Inventor: Group Art Unit:

Hiroji HANAWA, et al. 1753

Examiner Name:

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Examiner's Signature:

Date Considered:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not

in conformance and not considered. Include copy of this form with next communication to applicant.